


Evidence from transport measurements for YRh₆Ge₄ being a triply degenerate nodal semimetalYanglin Zhu¹,^{*} Xin Gui,² Yu Wang,¹ David Graf,³ Weiwei Xie,² Jin Hu,^{4,5} and Zhiqiang Mao^{1,*}¹*Department of Physics, Pennsylvania State University, University Park, Pennsylvania 16802, USA*²*Department of Chemistry, Louisiana State University, Baton Rouge, Louisiana 70803, USA*³*National High Magnetic Field Laboratory, Tallahassee, Florida 32310, USA*⁴*Department of Physics, University of Arkansas, Fayetteville, Arkansas 72701, USA*⁵*Institute for Nanoscience and Engineering, University of Arkansas, Fayetteville, Arkansas 72701, USA* (Received 21 September 2019; revised manuscript received 12 December 2019; published 17 January 2020)

We have investigated magnetotransport properties of YRh₆Ge₄, which was recently predicted to be a triply degenerate nodal semimetal. We find it exhibits remarkable signatures of a chiral anomaly, manifested by large negative longitudinal magnetoresistance, the quadratic field dependence of magnetoconductance and the planar Hall effect. Furthermore, we have also observed Shubnikov-de Haas (SdH) quantum oscillations in the magnetoresistivity measurements on this material. The analyses of the SdH data reveal two pointlike Fermi surfaces and these pockets are found to host nearly massless fermions. The small size of these Fermi pockets is in a good agreement with the theoretical prediction that the triply degenerate point in YRh₆Ge₄ is much closer to the Fermi level than previously demonstrated triply degenerate nodal semimetals such as MoP and WC. These results suggest YRh₆Ge₄ may serve as a model system to probe exotic properties of three-component fermions and understand their underlying physics.

DOI: [10.1103/PhysRevB.101.035133](https://doi.org/10.1103/PhysRevB.101.035133)**I. INTRODUCTION**

Topological semimetals (TSMs) are characterized by topologically protected band crossings near the Fermi level (FL), which leads to many exotic properties such as large magnetoresistance [1], high carrier mobility [1,2], chiral anomaly [3–7], and intrinsic anomalous Hall effect [8–12]. TSMs can be categorized by the band degeneracy at crossing points. Three-dimensional (3D) Dirac semimetals (DSMs) feature fourfold degenerate band crossing nodes (i.e., Dirac nodes), which were first theoretically predicted and then experimentally observed in Na₃Bi [13,14] and Cd₃As₂ [15–18]. When the spin degeneracy is lifted by breaking time-reversal symmetry or inversion symmetry, a DSM evolves into a Weyl semimetal (WSM), which is characterized by non-degenerate bands crossing, with each crossing point (i.e., Weyl node) having twofold degeneracy [19,20]. WSMs were first demonstrated in TaAs-class materials [20–26]. In addition to DSMs and WSMs, other forms of TSMs with three-, six-, and eightfold degenerate nodal points have been also proposed [27–32]. The three-degenerate nodal point TSM has been predicted in many materials such as WC- type families, including WC [31,33], ZrTe [33,34], MoP [35], and TaN [36]), and probed by ARPES in MoP [37] and WC [38]. In these materials, their band structures show band crossings between a doubly degenerate and a nondegenerate band near the FL. Such band crossings are protected by the combination of rotation and mirror symmetries [31,33,34,36,39]. Other materials predicted to have triply degenerate nodal points include Li₃NaN [40], LaPtBi [41], NaCu₃Te₂ [42,43], ZrO

[44], APd₃ (A = Sn, Pb) [45], TiB₂ [46,47], Cu₃TeO₆ [48], GdN [49], TaS [50], PtBi₂ [51], MoC [52], and carbon honeycombs (CHCs) [53]. All these predictions are still waiting for experimental verifications.

Materials with triply degenerate fermions are expected to exhibit properties distinct from DSMs and WSMs. For instance, they carry net Berry flux $|v| = 2$, leading to two surface Fermi arcs connecting the surface projections of triply degenerate points. When a magnetic field is applied, the Zeeman effect splits each threefold degenerate node into Weyl points, resulting in a topological phase transition. The chiral anomaly is also expected for triply degenerate nodal semimetals but shows different characteristics in comparison with WSMs. The negative longitudinal MR (LMR) induced by the chiral anomaly in triply degenerate nodal semimetals occurs only when the current is applied to the C₃ rotation axis. Among the predicted triply degenerate nodal TSMs, the chiral anomaly induced negative LMR is observed only in WC thus far [54]. Recently, intermetallic compounds RRh₆Ge₄ (R = Y, La, Lu) have been predicted to host triply degenerate points in their band structures [55]. These materials crystallize in the hexagonal structure with space group $P\bar{6}m2$, as shown in Fig. 1(a). Compared to previously demonstrated triply degenerate nodal semimetals, RRh₆Ge₄ is found to have triply degenerate points much closer to the FL (within a range of 50 meV from the Fermi level, contrasted to the 200 meV value in WC [38]). Therefore RRh₆Ge₄ provides an excellent platform to probe the exotic properties of triple-component fermions. In this paper, we report on the transport evidence of triply degenerate fermions of YRh₆Ge₄. We not only observed chiral anomaly induced negative LMR and planar Hall effect, but also probed the pointlike Fermi pockets hosting triple-component fermions through Shubnikov-de Haas (SdH)

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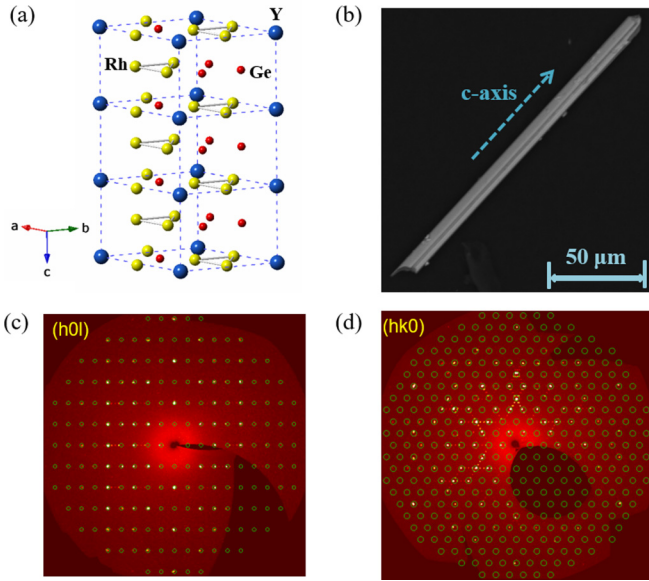


FIG. 1. (a) Crystal structure of YRh_6Ge_4 . (b) A crystal image of YRh_6Ge_4 . [(c) and (d)] Single-crystal x-ray diffraction precession image of the $(h0l)$ and $(hk0)$ planes in the reciprocal lattice of YRh_6Ge_4 at 300 K. The strong intensity spots can be fitted with the LaRh_6Ge_4 -type crystal structure.

quantum oscillations. Our findings establish a promising platform for exploring new exotic properties of three-component fermions and understanding their underlying physics.

II. EXPERIMENTAL

Single crystal YRh_6Ge_4 was synthesized through the flux method [56]. The Y pieces, Rh, Ge powder, and Bi granule were mixed with molar ratio 1:5:4:20 and loaded into an Al_2O_3 crucible, then sealed in a quartz tube under vacuum. The mixture was then heated up to 1050°C and held at this temperature for 48 hours for homogeneously melting, followed by a slow cooling down to 750°C at a rate of 2°C per hour and then a quick cooling down ($4^\circ\text{C}/\text{h}$) from 750°C to 550°C . Black rodlike crystals [Fig. 1(b)] can be obtained after removing the Bi flux by centrifugation.

To confirm the crystal structure of synthesized crystals, we performed single crystal x-ray diffraction measurements on a crystal with dimensions of $\sim 15 \times 15 \times 20 \mu\text{m}^3$ at room temperature using a single crystal diffractometer, Bruker Apex II (Mo radiation). We found our YRh_6Ge_4 crystals indeed have a hexagonal structure with the space group of $P\bar{6}m2$. In Figs. 1(c) and 1(d), we present the diffraction patterns of the $(h0l)$ and $(hk0)$ planes. All circled diffraction spots on these two scattering planes can be indexed with the hexagonal structure. The detailed analyses of these diffraction patterns yield the lattice parameters of $a = 7.067(3) \text{ \AA}$ and $c = 3.862(2) \text{ \AA}$, consistent with those previously reported in the literature [56]. Furthermore, we also observed satellite diffraction spots corresponding to a superlattice, i.e., those weak spots between circled spots in Figs. 1(c) and 1(d). The twinning assumption has been well examined and we can exclude the possibility of extra reflections due to crystal twinning. These weak spots cannot be indexed with the commensurate supercell

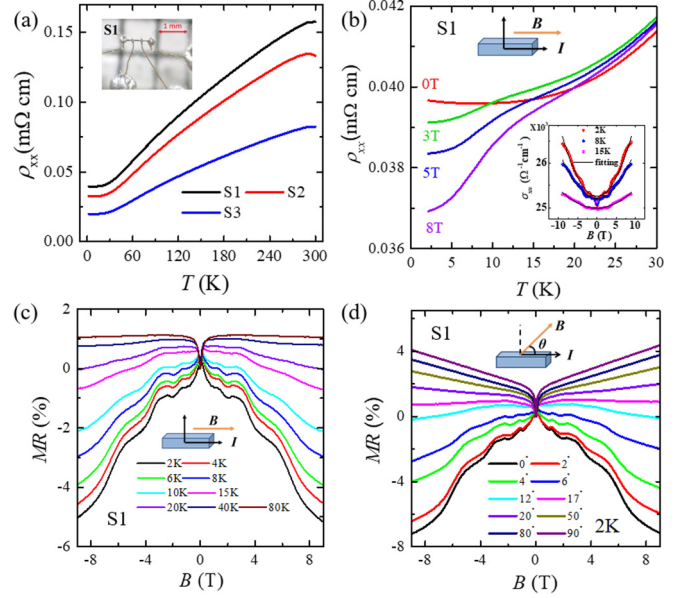


FIG. 2. (a) Temperature dependence of longitudinal resistivity under zero magnetic field for three different samples. Inset, the optical image of sample 1 (S1) with attached leads. (b) Temperature dependence of longitudinal resistivity under various magnetic fields for S1. Inset shows the field dependence of magnetoconductivity at various temperatures for S1; the solid black lines represent the fits to the B^2 dependence. (c) Field dependence of longitudinal magnetoresistivity $\Delta\rho/\rho_0 = [\rho(B) - \rho(B=0)]/\rho(B=0)$ at various temperatures for sample S1. (d) Field dependence of magnetoresistivity at 2 K under various field orientations measured in low 0–9 T field range. The insets in (c) and (d) show the schematic of the experimental setup.

structure of the previously reported LaRh_6Ge_4 -type structure [56]. The Q vector of the supercell structure extracted from Figs. 1(c) and 1(d) is ~ 0.176 , suggesting an incommensurate superlattice. Because of the presence of such superlattice reflections, the crystal structure cannot be refined based on our current measurements. The origin of such an incommensurate superlattice is yet to be clarified. We conducted systematic magnetotransport measurements on YRh_6Ge_4 single crystals using a standard four-probe method in a Physical Property Measurement System (PPMS, Quantum Design) and high-field measurements were carried out at the National High Magnetic Field Laboratory (NHMFL) in Tallahassee.

III. RESULTS AND DISCUSSIONS

Figure 2 shows the transport properties of YRh_6Ge_4 single crystals measured by PPMS. In these measurements, the electrical current was applied along the axial direction of the rod, which is the c axis of the crystal [Fig. 1(b)]. YRh_6Ge_4 exhibits metallic behavior in the temperature dependence of resistivity, but its residual resistivity shows strong sample dependence. Figure 2(a) presents the resistivity data at zero fields of three typical samples, labeled by S1, S2, and S3. Their residual resistivity is 0.04, 0.03, and 0.02 $\text{m}\Omega \text{ cm}$, respectively. These samples exhibit very different magnetotransport behavior and the large negative LMR associated with the chiral anomaly is observed only in S1-type samples. These differences can

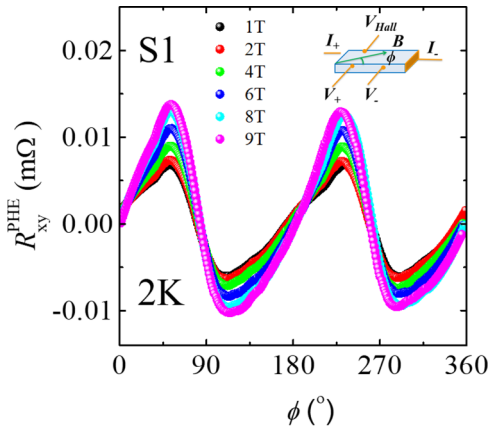


FIG. 3. The angle dependence of the planar Hall resistance R_{xy} under various magnetic fields at 2 K. Inset shows the schematics of the setup for the PHE measurements. The measurements were performed on a S1-type sample.

possibly be attributed to different chemical potential among these three types of samples, which will be discussed in great detail below. We will first focus on discussing the properties of the S1 sample and compare them with those of the S2 and S3 samples at the end. From Fig. 2(b), it can be seen that the resistivity ρ_{xx} of S1 becomes weakly temperature-dependent below 20 K with a slight upturn under zero field. The application of the magnetic field along the c axis suppresses ρ_{xx} for $T < 20$ K, indicating negative LMR. Field sweeps of magnetoresistivity (defined as $MR = [\rho(B) - \rho(0)]/\rho(0)$) at various fixed temperatures are presented in Fig. 2(c), from which we find the MR becomes remarkably negative below 15 K (about -5% at 9 T and 2 K), but positive above 15 K, with a valleylike cusp feature at zero fields. The valleylike cusp becomes more pronounced with the magnetic field perpendicular to the current direction owing to the absence of a negative magnetoresistance component in this setup [Fig. 3(d), also see supplementary Fig. S1]. Such a feature can be attributed to weak antilocalization (WAL). Our detailed magnetoresistivity data analysis based on the 3D WAL model [57,58] (see Ref. [59]) yields a quantum coherence length l_ϕ of 224 nm at $T = 2$ K, which is far less than the dimension of the samples used measurements.

Given YRh_6Ge_4 is predicted to possess a triply degenerate nodal point close to the FL, the most possible origin of the observed negative LMR is the chiral anomaly. This is indeed verified through our detailed experiments as described below. Before discussing chiral anomaly induced negative LMR in our samples, we should first rule out the conventional mechanisms of negative LMR such as current jetting [60] and microscopic disorder effects [61]. The former scenario usually occurs in samples with a small aspect ratio and high mobility. Since our single crystals are rodlike and the aspect ratio of the resistivity samples is large [~ 10 , see inset of Fig. 2(a)], current jetting is less likely. The latter effect has been reported in systems where microscopic disorders play a critical role, such as polycrystalline materials [62] and quantum well [61]. This effect should be minimized in single crystals. In fact, as will be shown below, the two Fermi pockets probed in our SdH oscillation measurements are consistent with the calculated

Fermi surface with nontrivial topology [55], which strongly indicates that the negative LMR seen in our experiments should originate from the carriers hosted by topologically non-trivial bands in YRh_6Ge_4 .

The angular dependence of negative LMR probed in our experiments is also consistent with the origin of chiral anomaly. As shown in Fig. 2(d), negative MR is gradually suppressed when the field is rotated away from the current direction, turning positive when the field tilt angle θ is above 12° and the WAL behavior becomes more significant. Since the chiral anomaly originates from the charge pumping between paired Weyl cones with opposite chirality and the resulting topological current responsible for the chiral anomaly is proportional to $\mathbf{E} \cdot \mathbf{B}$, where \mathbf{E} and \mathbf{B} represent electric and magnetic fields respectively [7,63], the observed gradual suppression of negative LMR with rotating magnetic field is in a good agreement with such a mechanism. Furthermore, we also find the nonoscillatory component of magnetoconductivity (i.e., the inverse of ρ_{xx} for $\mathbf{B} \parallel \mathbf{I}$) of the S1 sample follows \mathbf{B}^2 dependence [inset, Fig. 2(b)], consistent with the theoretically predicted scaling behavior of magneto-conductance stemming from the chiral anomaly [7,63]. We note a similar \mathbf{B}^2 dependence of magnetoconductance has been demonstrated in WSMs such as TaP [64] and GdPtBi [65].

In general, the chiral anomaly in WSMs can also lead to another exotic phenomenon—planar Hall effect (PHE) [66–69], which refers to the appearance of Hall voltage when \mathbf{E} and \mathbf{B} are coplanar. To further corroborate the chiral anomaly in YRh_6Ge_4 , we carried out PHE measurements on this material. The data obtained from these measurements are presented in Fig. 3, from which the planar Hall resistivity ρ_{xy}^{PHE} is found to show a twofold symmetry with the in-plane rotation of the magnetic field. However, we observed a clear deviation from the $\sin(2\phi)$ dependence expected for the PHE of WSMs, which can be attributed to the involvement of the ρ_{xx} component caused by the asymmetry of Hall contacts, which cannot be separated from ρ_{xy} .

As noted above, for triply degenerate nodal semimetals, a chiral anomaly is present only when both the current and magnetic fields are applied to the C_3 -rotation axis and this has been demonstrated in WC [54]. For YRh_6Ge_4 , since its C_3 -rotation axis is along the c axis [Figs. 1(a) and 1(b)], our experimental setup for LMR measurements [Figs. 2(c) and 2(d)] satisfies the conditions for observing chiral anomaly, so it is not surprising to observe the negative LMR in our experiments. However, the rodlike crystal does not allow us to apply current along with other crystallographic directions so that we could not check if the chiral anomaly is absent when the current and magnetic field are not along the C_3 -rotation axis. In addition to negative LMR, we also observed clear SdH oscillations. The systematic analyses of SdH oscillations will be given in a later section.

To further explore the exotic quantum transport properties of YRh_6Ge_4 , we performed high-field magnetotransport measurements in the NHMFL. Figure 4(a) displays the high-field LMR data under various field orientation angles θ , which were taken using a 31-T magnet. The variation of LMR with θ is consistent with the data taken in the PPMS [Fig. 2(d)]. Importantly, from these data, we found that the negative LMR continues to grow until the field is increased to 20 T,

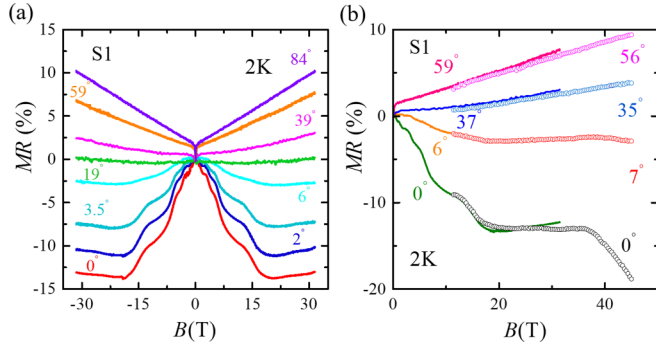


FIG. 4. (a) Field dependence of magnetoresistivity at 2 K under various field orientations measured using the 31-T magnet system at the NHMFL. (b) Field dependence of magnetoresistivity at 2 K measured under a few field orientations in both the 31-T and 45-T magnet systems for S1.

reaching $\sim -14\%$ near 20 T. Above 20 T, the SdH oscillations probed in the low-field range vanish and the LMR exhibits a plateau-like feature. This feature was made much clear in the measurements conducted in the 45-T hybrid magnet which allows measurements in the 11–45 T field range. In Fig. 4(b), we put together the data taken in the 31-T and 45-T magnets for a few field orientation angles. These data clearly show the plateau for $B \parallel I$ ($\theta = 0^\circ$) extends to ~ 35 T, beyond which LMR displays a steep drop. The tilt of the magnetic field has a strong effect on the LMR drop near 35 T. When θ is increased to 7° , the drop near 35 T almost disappears, but the plateau extends to a much greater field range (20–40 T).

This plateau as well as the drop near 35 T may reflect new exotic phenomena in the quantum limit, or originate from SdH oscillations of another larger Fermi pocket, as will be discussed below.

The observation of the chiral anomaly in YRh_6Ge_4 suggests a possible Weyl state emerging under the magnetic field. As indicated above, the theory predicts that triply degenerate nodes could split into Weyl nodes by the Zeeman effect when the magnetic field is applied along the C_3 symmetry axis [38,54]. All signatures related to the chiral anomaly seen in our experiment agree well with this theoretical scenario. As indicated above, among all the previously predicted triply degenerate nodal TSMs, WC is the only material that was found to show the chiral anomaly induced negative LMR. This material hosts multiple triply degenerate nodes; the one which is the nearest to the FL is located at ~ 200 meV below E_F . In contrast, the triply degenerate nodes in YRh_6Ge_4 is much closer to E_F according to the band structure calculations, ~ 50 meV above E_F [55]. Our analyses of SdH oscillations provide strong support for this prediction, as will be discussed below.

As seen in Fig. 2(c), the SdH oscillations in YRh_6Ge_4 start to emerge from ~ 1 T; it decays very fast when the magnetic field is rotated from parallel to perpendicular to the current direction and disappears when the field tilt angle θ is increased above 17° [Fig. 2(d)], indicating highly anisotropic energy bands. The fast Fourier transform (FFT) analyses of the oscillation pattern with the background being subtracted [Fig. 5(a)] reveal two oscillation frequencies, i.e., $F_\alpha = 2T$ and $F_\beta = 6.8T$, as shown in Fig. 5(b). From the fits of the temperature

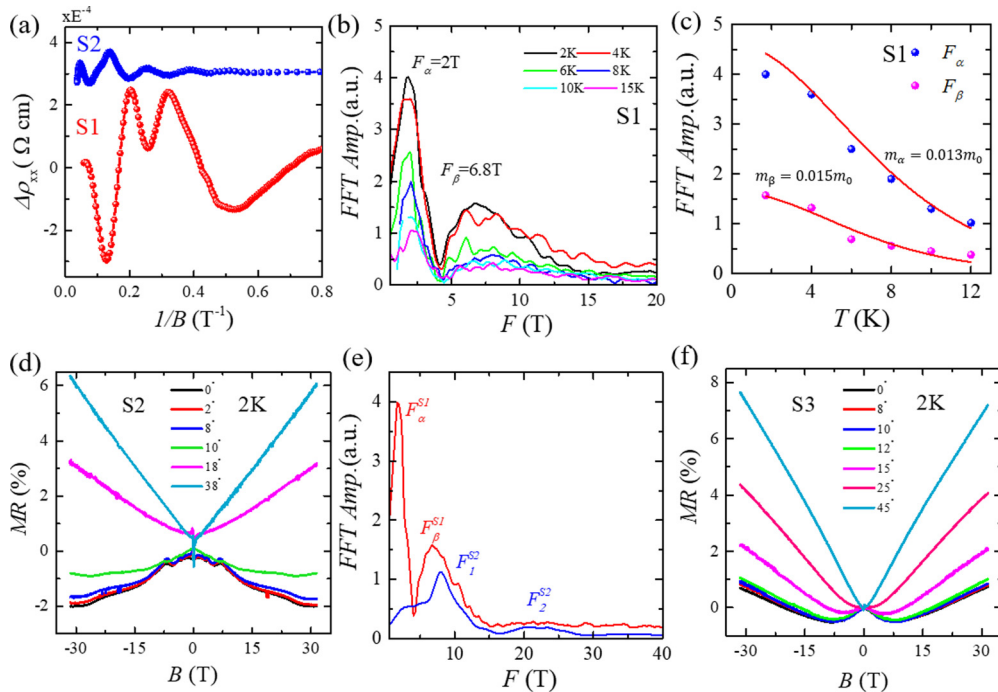


FIG. 5. (a) The SdH oscillation patterns after subtracting nonoscillating background for S1 (red curve) and S2 (blue curve). The data of S2 have been shifted for clarity. (b) FFT spectra of the SdH oscillations for $B \parallel I$ for S1. (c) The fits of the FFT amplitudes of the SdH oscillations by the temperature damping factor R_T in the LK formula. [(d) and (f)] Field dependences of magnetoresistivity at 2 K under various field orientations for S2 (d) and S3 (f). (e) The FFT spectra of the SdH oscillations at 2 K for S1 and S2.

dependences of the FFT oscillation amplitudes by the temperature damping factor of the Lifshitz-Kosevich formula, $R_T = \alpha T m^* / [m_0 B \sinh(\alpha T m^* / m_0 B)]$ where $\alpha = (2\pi^2 k_B m_0) / (\hbar e)$ [Fig. 5(c)], the effective mass m^* is estimated to be $0.013 m_0$ and $0.015 m_0$ (m_0 , free electron mass), respectively, for the F_α and F_β bands, indicating the quasiparticles hosted by F_α and F_β bands in YRh_6Ge_4 are nearly massless. We note that the value of m^* extracted from the fit of the temperature dependence of FFT amplitude depends on the range of magnetic field used for FFT analyses in some cases [70]. The m^* values given above for YRh_6Ge_4 are estimated from the analyses of the oscillation pattern in the 0.3–20 T field range. We also performed the FFT analyses for the SdH oscillations in the 0.4–9 T range, probed in the measurements by the PPMS. m^* extracted from these analyses is $0.012 m_0$ and $0.013 m_0$ for the F_α - and F_β -bands, respectively, comparable to the m^* derived from the analyses in the 0.3–20 T field range.

From the quantum oscillation frequencies extracted above, we can also evaluate the extremal cross-section area A_F of the Fermi surface comprised of the F_α and F_β bands using the Onsager relation $F = (\Phi_0 / 2\pi^2) A_F$. The frequency of $F_\alpha = 2.0 T$ and $F_\beta = 6.8 T$ correspond to $A_{F,\alpha} = 0.019 \text{ nm}^{-2}$ and $A_{F,\beta} = 0.065 \text{ nm}^{-2}$, respectively. Such small values of A_F indicate very small Fermi surfaces. From comparison with the calculated band structure and Fermi surfaces of YRh_6Ge_4 [55], we infer that the two calculated small electron pockets at point A at the Brillouin zone boundary (Fig. 6(b) in Ref. [55]) should be comprised of the F_α and F_β bands probed in our experiments. Given the quantum oscillation frequencies of these two bands are so low, their quantum limit should be reached above 15 T, which can explain the vanishing of the SdH oscillations associated with these two bands above 15 T. Regarding the magnetoresistance's plateau in the high-field regime (20–35 T) as well as its drop above 35 T, there are two possible origins. One is that it may reflect a new quantum state emerging in the quantum limit. Theory predicts the quantum limit could possibly incur ordered states such as a charge-density wave or spin-density wave [71–73]. However, we cannot tell if such states occur to YRh_6Ge_4 in its quantum limit state only in terms of our current data. The other possibility is that the magnetoresistance's drop near 35 T originates from the SdH oscillations caused by other larger Fermi pockets. Band structure calculations have shown the existence of one large electron pocket and one large hole pocket besides two small electron pockets hosting three-component fermions [55]. High-field measurements above 45 T are needed to verify if this is the case, which is beyond the scope of this work.

Finally, let's compare the magnetotransport properties of sample S1 with those of samples S2 and S3. The MR data of samples S2 and S3 at 2 K under various field orientations are presented in Figs. 5(d) and 5(f), respectively. Sample S2 also exhibits negative MR for $\theta < 12^\circ$ and remarkable weak-antilocalization behavior for $\theta > 12^\circ$, but its magnitude of LMR ($\sim 2\%$ even at 30 T) is much smaller than that of sample S1 ($\sim 13\%$ at 30 T). SdH oscillations are also observed in S2, but its oscillation pattern looks very different from that of S1 [see Fig. 5(a)] and its oscillation frequencies derived from the FFT analyses are $F_1 = 8 T$ and $F_2 = 21 T$ respectively, as shown in Fig. 5(e) where the FFT spectrum

of S1 at 2 K is also included for comparison. For S3, its negative LMR is very small ($< 1\%$); when the field is above 9 T, its MR becomes positive. The weak-antilocalization seen in S1 and S2 also disappears in S3. Moreover, SdH oscillations also become barely observable in S3 [Fig. 5(f)]. These observations imply that, although the band structure calculations [55] show YRh_6Ge_4 has triply degenerate points at $\sim 50 \text{ mV}$ above the FL, in the real synthesized crystals, the chemical potential is sample dependent and may be away from the calculated FL for some samples due to the self-doping caused by nonstoichiometric chemical composition. In fact, the stoichiometric control in bulk crystal growth has been known as a challenging problem which is hard to be overcome. The crystal growth of YRh_6Ge_4 has apparently encountered such a problem. For S1, the chemical potential is supposed to be close to the theoretical calculated E_F in Ref. [55], since its SdH oscillations probe the two calculated small electron pockets hosting three-component fermions as discussed above. However, in S2, its SdH oscillations frequencies do not show the $F_\alpha = 2 T$ component, but only the $F_1 = 8 T$ and $F_2 = 21 T$ components, implying its chemical potential should be lower than that of S1 so that the F_α band is not occupied. The $F_1 = 8 T$ component should arise from the β pocket, while the $F_2 = 21 T$ likely stems from the trivial electron pocket. The chemical potential of S3 should be much lower than those of S1 and S2 such that its magnetotransport properties are dominated by the trivial bands.

IV. CONCLUSION

In summary, we have synthesized the single crystals of YRh_6Ge_4 and performed systematic magnetotransport studies on this material. We observed remarkable signatures of a chiral anomaly which can be attributed to the topological phase transition from the triply degenerate nodal semimetal state to the Weyl semimetal state. Furthermore, we also probed two pointlike electron pockets through SdH oscillations, which agrees well with the two calculated small electron pockets which host three-component fermions. These results also demonstrate that the triply degenerate nodal points in YRh_6Ge_4 are indeed much closer to the FL than those in previously established triply degenerate nodal semimetals such as MoP and WC. Therefore our work establish a new promising playground for probing new exotic properties of triply degenerate nodal semimetal states and understanding their underlying physics.

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